NSN 5961-00-026-8886

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View Online at https://aerobasegroup.com/nsn/5961-00-026-8886 **Inclosure Material:** Metal **Overall Length:** Between 0.195 inches and 0.215 inches Overall Diameter: 0.460 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Thread Size:** 0.138 inches **Criticality Code Justification:** Feat **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 120.0 breakdown voltage, collector-to-emitter, base open and 10.0 breakdown voltage, emitter-to-base, collector open **Current Rating Per Characteristic:** 500.00 milliamperes source cutoff current and 15.00 microamperes zero-gate-voltage source current preset **Power Rating Per Characteristic:** 1.0 watts small-signal input power, common-collector **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius ambient air **Special Features:** Item must comply with rqmt of desc production standard no. L00936; junction pattern arrangement: npn **Thread Series Designator:** Unc **Terminal Type And Quantity:** 3 uninsulated wire lead Shelf Life: N/a **Unit Of Measure:**

No

Demilitarization:

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